

PM50RVA120

FLAT-BASE TYPE
INSULATED PACKAGE

PM50RVA120



FEATURE

- 3 ϕ 50A, 1200V Current-sense IGBT for 20kHz switching
- 15A, 1200V Current-sense regenerative brake IGBT
- Monolithic gate drive & protection logic
- Detection, protection & status indication circuits for over-current, short-circuit, over-temperature & under-voltage
- Acoustic noise-less 7.5kW class inverter application
- UL Recognized

Yellow Card No. E80276(N)

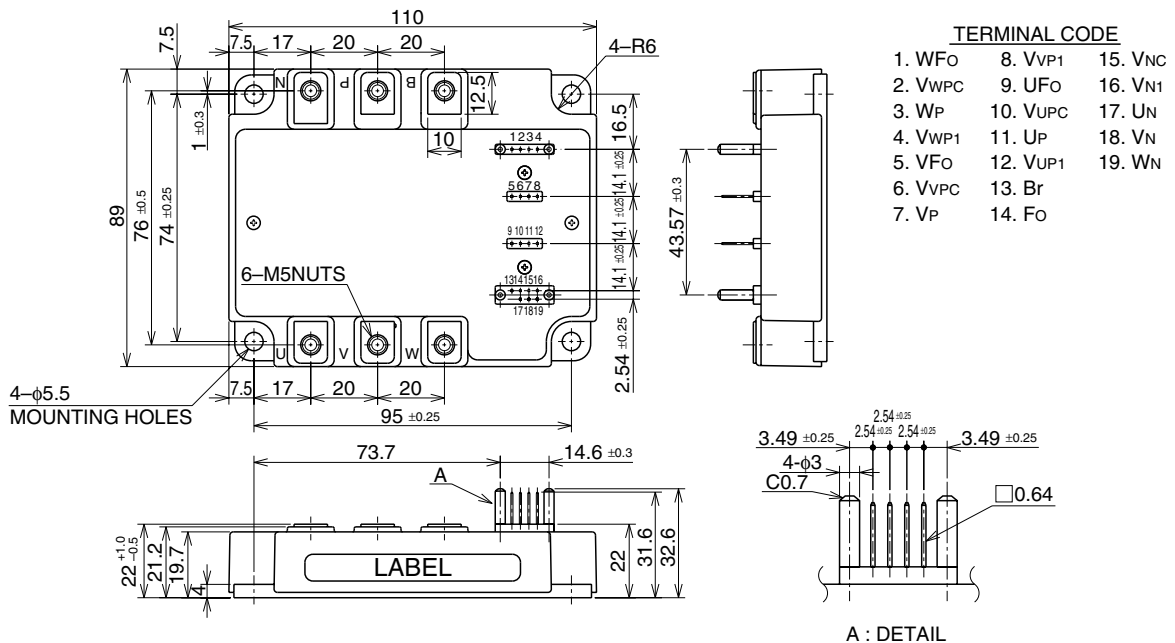
File No. E80271

APPLICATION

General purpose inverter, servo drives and other motor controls

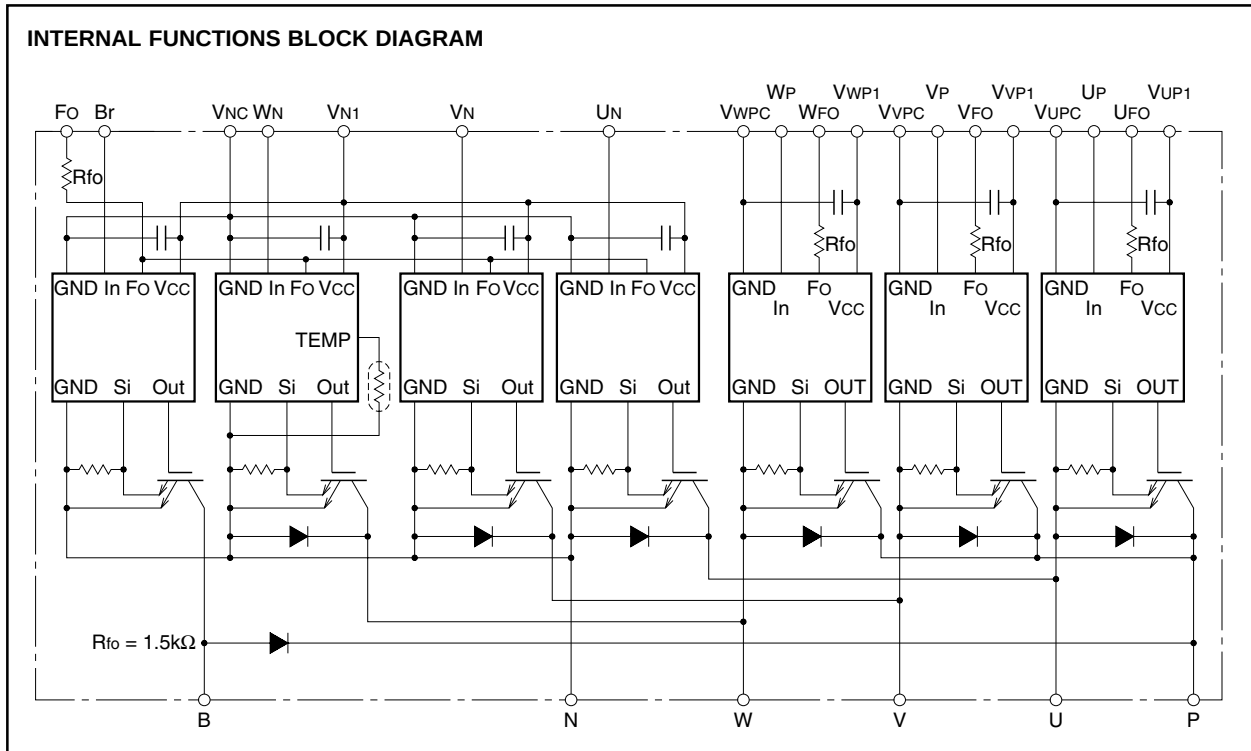
PACKAGE OUTLINES

Dimensions in mm



PM50RVA120

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INTERNAL FUNCTIONS BLOCK DIAGRAM

MAXIMUM RATINGS ($T_j = 25^\circ\text{C}$, unless otherwise noted)

INVERTER PART

Symbol	Parameter	Condition	Ratings	Unit
V_{CES}	Collector-Emitter Voltage	$V_D = 15\text{V}$, $V_{CIN} = 15\text{V}$	1200	V
$\pm I_C$	Collector Current	$T_c = 25^\circ\text{C}$	50	A
$\pm I_{CP}$	Collector Current (Peak)	$T_c = 25^\circ\text{C}$	100	A
P_C	Collector Dissipation	$T_c = 25^\circ\text{C}$	338	W
T_j	Junction Temperature		$-20 \sim +150$	$^\circ\text{C}$

BRAKE PART

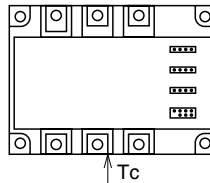
Symbol	Parameter	Condition	Ratings	Unit
V_{CES}	Collector-Emitter Voltage	$V_D = 15\text{V}$, $V_{CIN} = 15\text{V}$	1200	V
I_C	Collector Current	$T_c = 25^\circ\text{C}$	15	A
I_{CP}	Collector Current (Peak)	$T_c = 25^\circ\text{C}$	30	A
P_C	Collector Dissipation	$T_c = 25^\circ\text{C}$	134	W
$V_{R(DC)}$	FWDi Rated DC Reverse Voltage	$T_c = 25^\circ\text{C}$	1200	V
I_F	FWDi Forward Current	$T_c = 25^\circ\text{C}$	15	A
T_j	Junction Temperature		$-20 \sim +150$	$^\circ\text{C}$

CONTROL PART

Symbol	Parameter	Condition	Ratings	Unit
V_D	Supply Voltage	Applied between : $V_{UP1}-V_{UPC}$ $V_{VP1}-V_{VPC}$, $V_{WP1}-V_{WPC}$, $V_{N1}-V_{NC}$	20	V
V_{CIN}	Input Voltage	Applied between : U_P-V_{UPC} , V_P-V_{VPC} W_P-V_{WPC} , $U_N \cdot V_N \cdot W_N \cdot B_r-V_{NC}$	20	V
V_{FO}	Fault Output Supply Voltage	Applied between : $U_{FO}-V_{UPC}$, $V_{FO}-V_{VPC}$, $W_{FO}-V_{WPC}$ F_O-V_{NC}	20	V
I_{FO}	Fault Output Current	Sink current at U_{FO} , V_{FO} , W_{FO} and F_O terminal	20	mA

PM50RVA120**FLAT-BASE TYPE
INSULATED PACKAGE****TOTAL SYSTEM**

Symbol	Parameter	Condition	Ratings	Unit
V _{CC(Prot)}	Supply Voltage Protected by SC	V _D = 13.5 ~ 16.5V, Inverter Part, T _j = 125°C Start	800	V
V _{CC(surge)}	Supply Voltage (Surge)	Applied between : P-N, Surge value or without switching	1000	V
T _C	Module Case Operating Temperature	(Note-1)	-20 ~ +100	°C
T _{stg}	Storage Temperature		-40 ~ +125	°C
V _{iso}	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base, AC 1 min.	2500	V _{rms}

(Note-1) T_C measurement point is below. (3mm depth at the center of the side of base plate)**ELECTRICAL CHARACTERISTICS** (T_j = 25°C, unless otherwise noted)**INVERTER PART**

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	V _D = 15V, I _C = 50A	—	2.65	3.30	V
		V _{CIN} = 0V		2.75	3.35	
V _{EC}	FWDi Forward Voltage	-I _C = 50A, V _D = 15V, V _{CIN} = 15V	—	2.5	3.5	V
t _{on}	Switching Time	V _D = 15V, V _{CIN} = 0V↔15V V _{CC} = 600V, I _C = 50A T _j = 125°C Inductive Load (upper and lower arm)	0.4	0.9	2.3	μs
t _{rr}			—	0.2	0.3	
t _{c(on)}			—	0.4	1.0	
t _{off}			—	2.4	3.4	
t _{c(off)}			—	0.7	1.2	
I _{CES}	Collector-Emitter Cutoff Current	V _{CE} = V _{CES} , V _{CIN} = 15V	—	—	1	mA
					10	

BRAKE PART

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	V _D = 15V, I _C = 15A	—	2.50	3.30	V
		V _{CIN} = 0V		2.20	3.20	
V _{FM}	FWDi Forward Voltage	I _F = 15A	—	2.50	3.50	V
I _{CES}	Collector-Emitter Cutoff Current	V _{CE} = V _{CES} , V _{CIN} = 15V	—	—	1	mA
					10	

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Symbol	Parameter	Test Condition		Limits			Unit
				Min.	Typ.	Max.	
Id	Circuit Current	VD = 15V, V _{CIN} = 15V	V _{N1} -V _{NC}	—	44	60	mA
			V*P ₁ -V*P _C	—	13	18	
V _{th(ON)}	Input ON Threshold Voltage	Applied between : UP-VUPC, VP-VVPC, WP-VWPC UN • VN • WN • Br-VNC		1.2	1.5	1.8	V
V _{th(OFF)}	Input OFF Threshold Voltage			1.7	2.0	2.3	
OC	Over Current Trip Level	−20 ≤ T _J ≤ 125°C, VD = 15V, Break part		22	—	—	A
SC	Short Circuit Trip Level	−20≤ T _J ≤ 125°C, VD = 15V	Inverter part	59	—	—	A
			Brake part	—	52	—	
t _{off(OC)}	Over Current Delay Time	VD = 15V, Break part		—	10	—	μs
t _{off(SC)}	Short Circuit Current Delay Time	VD = 15V		—	10	—	μs
OT	Over Temperature Protection	Base-plate	Trip level	111	118	125	°C
OT _r		Temperature detection, VD = 15V	Reset level	—	100	—	
UV	Supply Circuit Under-Voltage Protection	−20 ≤ T _J ≤ 125°C	Trip level	11.5	12.0	12.5	V
UV _r			Reset level	—	12.5	—	
I _{FO(H)}	Fault Output Current	VD = 15V, V _{FO} = 15V (Note-2)	—	—	0.01	mA	
I _{FO(L)}			—	10	15		
t _{FO}	Minimum Fault Output Pulse Width	VD = 15V (Note-2)	1.0	1.8	—	ms	

(Note-2) Fault output is given only when the internal SC, OT & UV protection.
 Fault output of OT protection operate by lower arm.
 Fault output of OT, UV protection given pulse while over level.

THERMAL RESISTANCES

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
R _{th(j-c)Q}	Junction to case Thermal Resistances	Inverter IGBT part (per 1/6 module)	—	—	0.37	°C/W
R _{th(j-c)F}		Inverter FWDi part (per 1/6 module)	—	—	0.70	
R _{th(j-c)Q}		Brake IGBT part	—	—	0.93	
R _{th(j-c)F}		Brake FWDi part	—	—	1.50	
R _{th(c-f)}	Contact Thermal Resistance	Case to fin, Thermal grease applied (per 1 module)	—	—	0.027	

MECHANICAL RATINGS AND CHARACTERISTICS

Symbol	Parameter	Test Condition	Limits			Unit
			Min.	Typ.	Max.	
—	Mounting torque	Mounting part screw : M5	2.5	3.0	3.5	N • m
—	Mounting torque	Main terminal screw : M5	2.5	3.0	3.5	N • m
—	Weight	—	—	560	—	g

RECOMMENDED CONDITIONS FOR USE

Symbol	Parameter	Test Condition	Recommended value	Unit
V _{CC}	Supply Voltage	Applied across P-N terminals	≤ 800	V
V _D	Control Supply Voltage	Applied between : VUP1-VUPC, VVP1-VVPC VWP1-VWPC, VN1-VNC (Note-3)	15 ± 1.5	V
V _{CIN(ON)}	Input ON Voltage	Applied between : UP-VUPC, VP-VVPC, WP-VWPC UN • VN • WN • Br-VNC	≤ 0.8	V
V _{CIN(OFF)}	Input OFF Voltage		≥ 4.0	
t _{dead}	Arm Shoot-through Blocking Time	For IPM's each input signals	≥ 3.0	μs
f _{PWM}	PWM Input Frequency	Using Application Circuit input signal of IPM, Sinusoidal PWM VVVF inverter	≤ 20	kHz

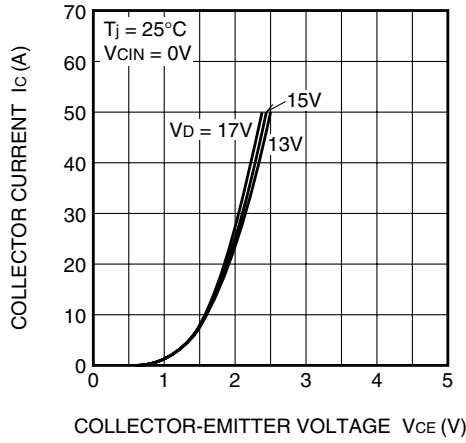
(Note-3) With ripple satisfying the following conditions dv/dt swing ≤ ±5V/μs, Variation ≤ 2V peak to peak

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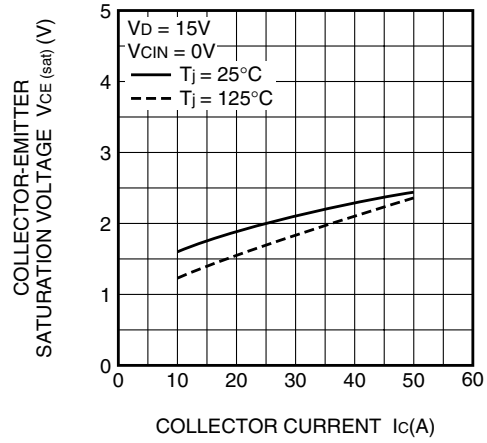
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PERFORMANCE CURVES (Inverter Part)

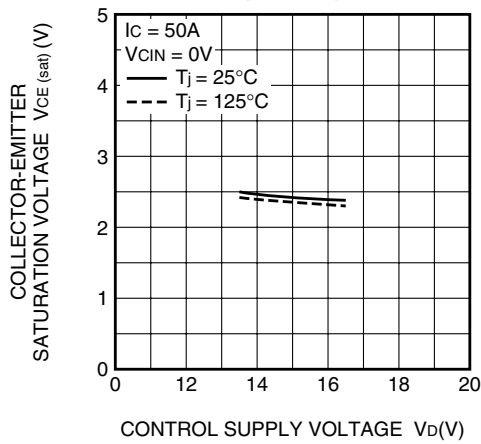
OUTPUT CHARACTERISTICS
(TYPICAL)



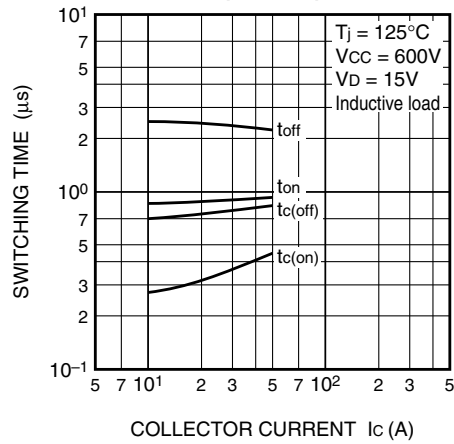
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



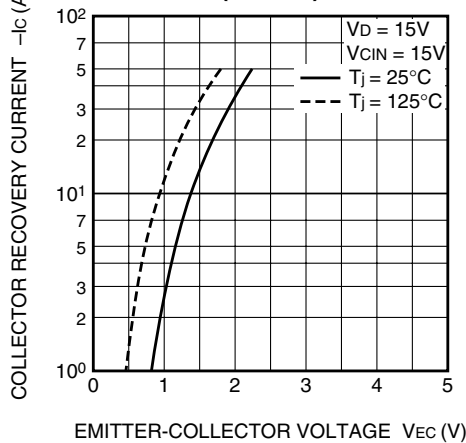
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



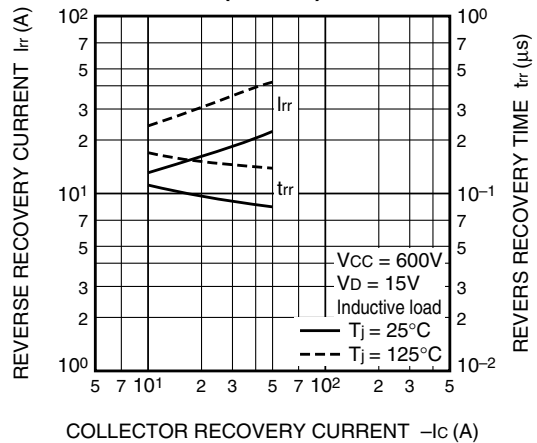
SWITCHING CHARACTERISTICS
(TYPICAL)



DIODE FORWARD CHARACTERISTICS
(TYPICAL)



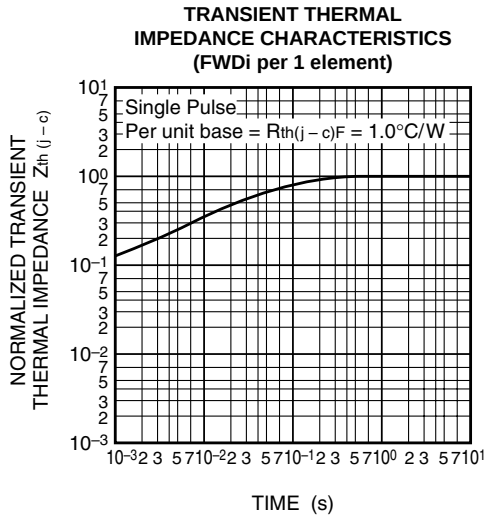
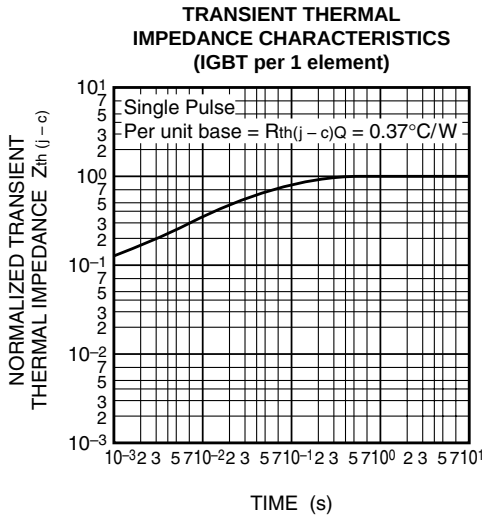
DIODE REVERSE RECOVERY CHARACTERISTICS
(TYPICAL)



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PERFORMANCE CURVES (Inverter Part)

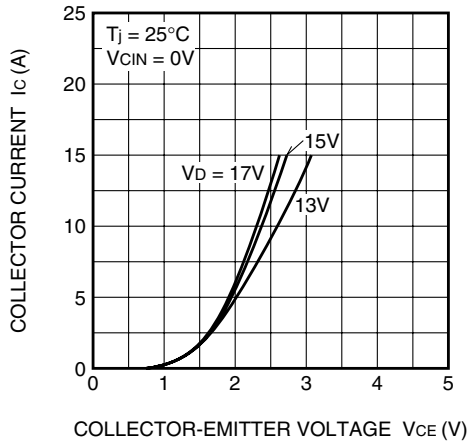


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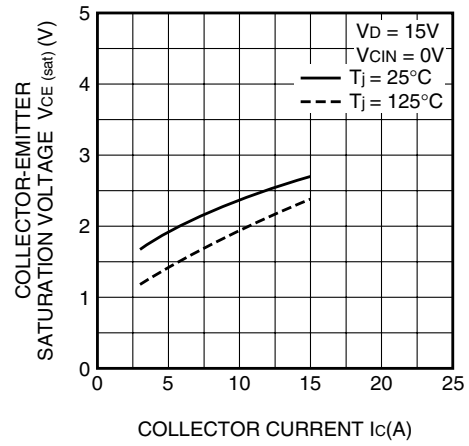
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PERFORMANCE CURVES (Brake Part)

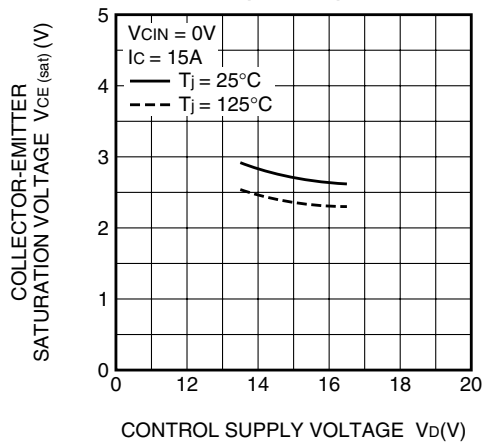
OUTPUT CHARACTERISTICS
(TYPICAL)



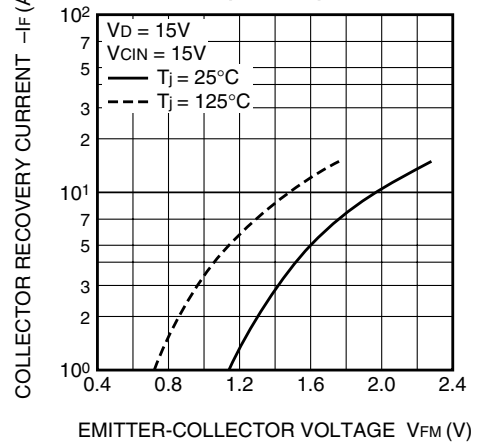
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



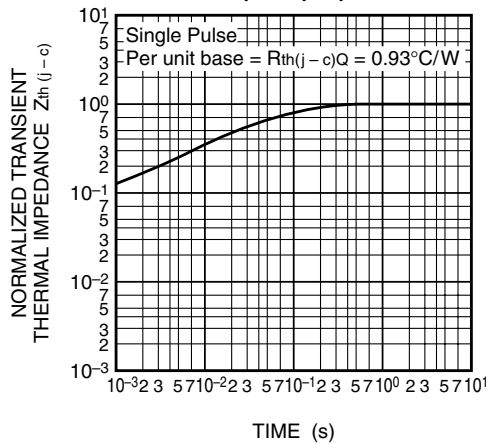
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



DIODE FORWARD CHARACTERISTICS
(TYPICAL)



TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(IGBT part)



TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(FWDi part)

